

AMENDMENTS TO THE SPECIFICATION

Please replace the last paragraph on page 1 that extends onto page 2 with the following paragraph:

An example of an active-matrix type organic EL display which has been proposed is shown in FIG. 19. This drawing shows one pixel, and a driving element, etc., which are disposed around this one pixel. In this active-matrix type organic EL display, switching transistor 34, driving transistor 37, and capacity 36 are provided for each pixel 35 made of ~~anorganic~~ an organic EL element. These elements are connected to a driving circuit by way of signal line 31, power supply line 32, scanning line 33, and capacity line 38. Reference numeral 19 is an electrode of pixel 35. The purpose of using plural transistors is to enhance the reliability by improving off-current, lowering the deterioration of characteristics caused by impressing a voltage on the transistor.

Please replace the second complete paragraph on page 3 with the following paragraph:

Also, in an active-matrix type organic EL display in FIG. 19, the aperture ratio is as small as 10% because the light from the organic EL element as a pixel 35 is blocked by four lines of wiring 31 to 33, and 38, ~~two~~ two transistors 34 and 37, and capacity 36. Accordingly, in order to improve the aperture ratio of the active-matrix type organic EL display, it is necessary to decrease the area of the thin film transistor or the wiring.

Please replace the first complete paragraph on page 13 with the following paragraph:

According to the number "n" which is the number of the organic EL elements (pixels) which are driven by the semiconductor element of the unit block, the number of the unit blocks which is disposed at one organic EL display can be decreased to $1/n$. Also, as the number n increases, the cost reducing effect, effect of reduced ~~erres~~ errors in disposing the unit block, and effect of decreasing wiring errors are increased.

Please replace the last paragraph on page 21 that extends onto page 22 with the following paragraph:

In this display, pixel 35 which is made of an organic EL element and pixel electrode 19 are disposed at each pixel position, and switching transistor 34, driving transistor 37, capacity 36 are provided as semiconductor elements for driving each pixel 35. Also, these elements are connected to a driving circuit which is disposed in a peripheral part of the display, by signal line 31, power supply line 32, scanning line 32 33, and capacity line 38.